AM27S19, ‘S19A, ‘LS19, ‘LS19SA

256-Bit (32x8) Bipolar PROM

The AM27S19 (32 words by 8 bits) is a Schottky TTL Programmable Read-Only Memory (PROM).

This device is available in three-state (AM27S19) output versions. These outputs are compatible with low-power Schottky bus standards capable of satisfying the requirements of a variety of microprogrammable controls, mapping functions, code conversions, or logic replacements. Easy word depth expansion is facilitated by an active LOW output enable ($\overline{G}$).

Rochester Electronics Manufactured Components

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All recreations are done with the approval of the OCM.

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceeds the OCM data sheet.

Quality Overview

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-38535
    - Class Q Military
    - Class V Space Level
- Qualified Suppliers List of Distributors (QSLD)
    - Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer’s datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OEM specifications. ‘Typical’ values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.

Am27S19/27S19A
Am27S19SA/27LS19

256-Bit (32x8) Bipolar PROM

Advanced Micro Devices

DISTINCTIVE CHARACTERISTICS

- Ultra high speed
- Highly reliable, ultra-fast programming Platinum-Silicide fuses
- High-programming yield
- Low-current PNP inputs
- High-current open collector and three-state outputs
- Fast chip select

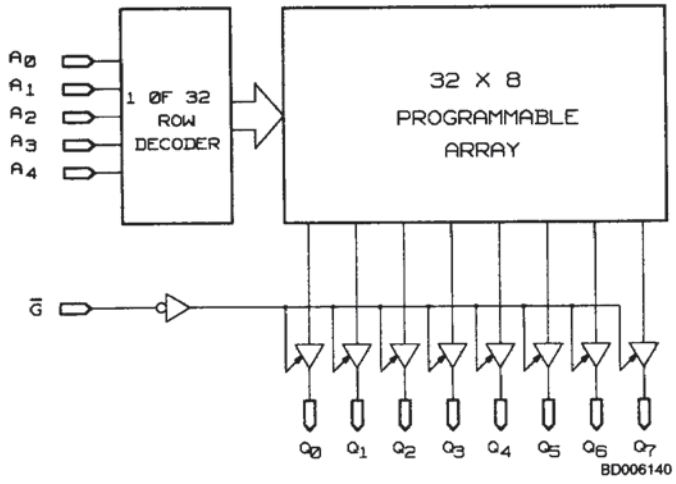
GENERAL DESCRIPTION

The Am27S19 (32 words by 8 bits) is a Schottky TTL Programmable Read-Only Memory (PROM).

This device is available in three-state (Am27S19) output versions. These outputs are compatible with low-power Schottky bus standards capable of satisfying the requirements of a variety of microprogrammable controls, mapping functions, code conversions, or logic replacements. Easy word depth expansion is facilitated by an active LOW output enable ($\overline{G}$).

This device is also available in a low-power version Am27LS19.

BLOCK DIAGRAM



PRODUCT SELECTOR GUIDE

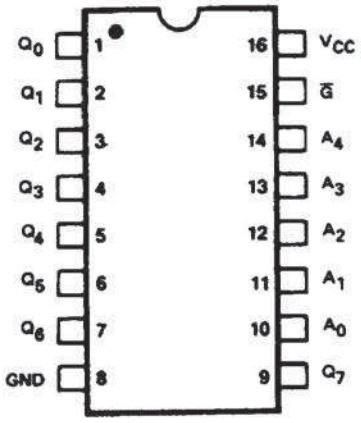
Three-State Part Number	Am27S19SA		Am27S19A		Am27S19		Am27LS19	
Address Access Time	15 ns	20 ns	25 ns	35 ns	40 ns	50 ns	55 ns	70 ns
Operating Range	C	M	C	M	C	M	C	M

5

Publication # 03209 Rev. E Amendment /0
Issue Date: January 1989

CONNECTION DIAGRAMS
Top View

DIPs*



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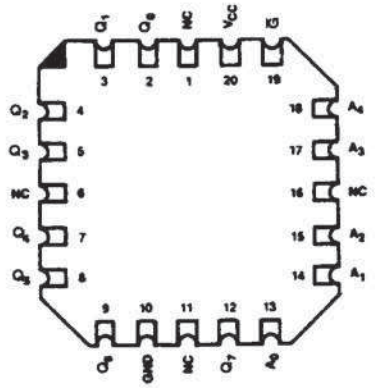
LCC**



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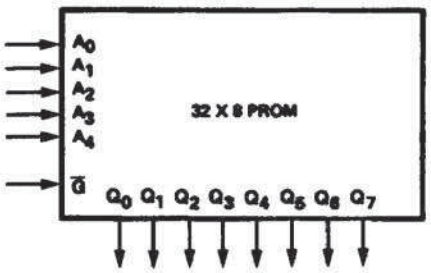
Note: Pin 1 is marked for orientation.
*Also available in a 16-pin Flatpack. Pinout identical to DIPs.
**Also available in a 16-pin Plastic Leaded Chip Carrier. Pinout identical to LCC.

LOGIC SYMBOL



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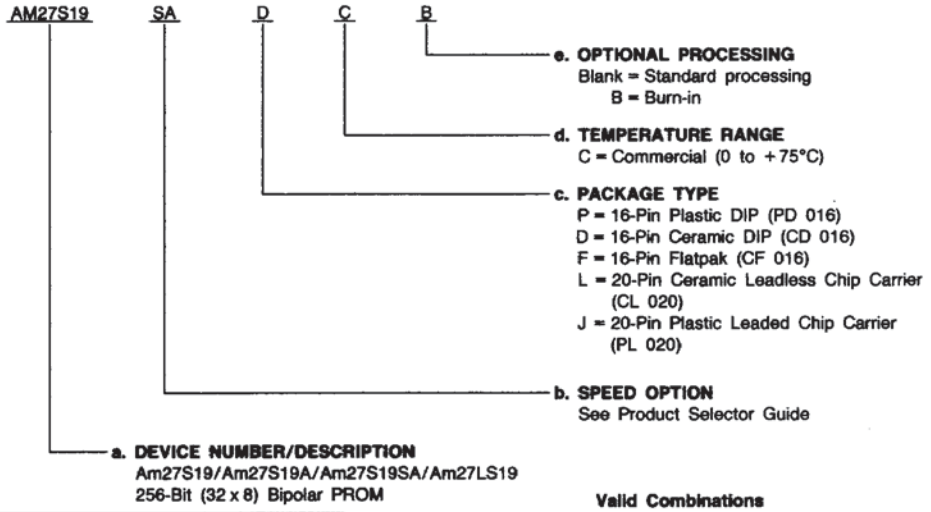
ORDERING INFORMATION

Standard Products

AMD standard products are available in several packages and operating ranges. The order number (Valid Combination) is formed by a combination of: **a. Device Number**
b. Speed Option (if applicable)
c. Package Type
d. Temperature Range
e. Optional Processing



Valid Combinations	
AM27S19	PC, PCB, DC, DCB, FC, FCB, LC, LCB, JC, JCB
AM27S19A	
AM27S19SA	
AM27LS19	

Valid Combinations

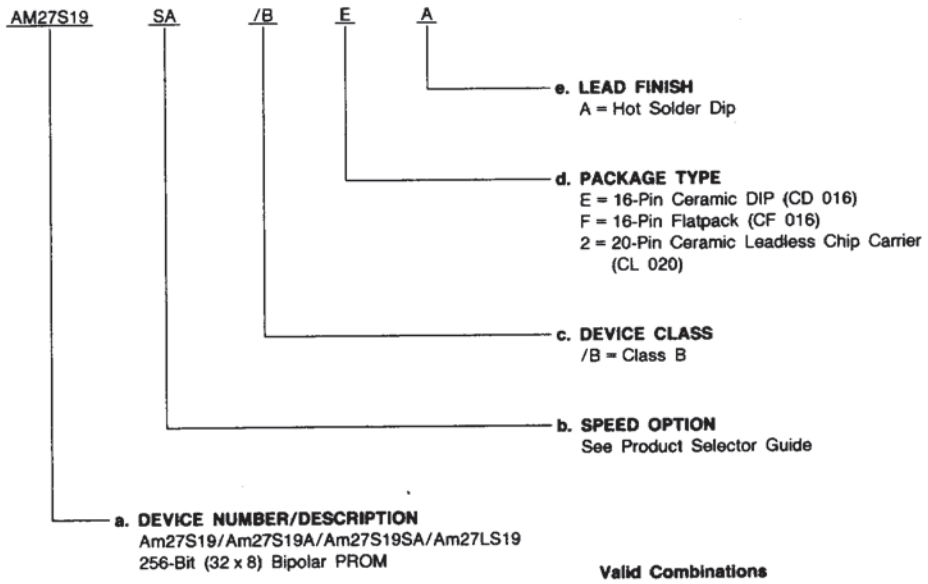
Valid Combinations list configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations, to check on newly released combinations, and to obtain additional data on AMD's standard military grade products.

5

MILITARY ORDERING INFORMATION

APL Products

AMD products for Aerospace and Defense applications are available in several packages and operating ranges. APL (Approved Products List) products are fully compliant with MIL-STD-883C requirements. The order number (Valid Combination) for APL products is formed by a combination of: **a. Device Number**
b. Speed Option (if applicable)
c. Device Class
d. Package Type
e. Lead Finish



Valid Combinations	
AM27S19	/BEA, /BFA, /B2A
AM27S19A	
AM27S19SA	
AM27LS19	

Valid Combinations

Valid Combinations list configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations or to check for newly released valid combinations.

Group A Tests

Group A tests consist of Subgroups 1, 2, 3, 7, 8, 9, 10, 11.

MILITARY BURN-IN

Military burn-in is in accordance with the current revision of MIL-STD-883, Test Method 1015, Conditions A through E. Test conditions are selected at AMD's option.

PIN DESCRIPTION

$A_0 - A_4$ Address Inputs
The 5-bit field presented at the address inputs selects one of 32 memory locations to be read from.

$Q_0 - Q_7$ Data Output Port
The outputs whose state represents the data read from the selected memory locations

$\overline{G}$ Output Enable
Provides direct control of the Q output three-state buffers. Outputs disabled forces all open-collector outputs to an OFF state and all three-state outputs to a floating or high-impedance state.

Enable = $\overline{G}$

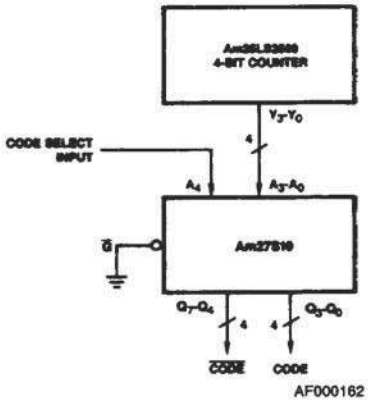
Disable = G

V_{CC} Device Power Supply Pin
The most positive of the logic power supply pins.

GND Device Power Supply Pin
The most negative of the logic power supply pins.

FUNCTIONAL DESCRIPTION

The Am27S19 PROM may be used as a code converter. Examples include conversion of hexadecimal, octal of BCD to seven segment display drive format. In many code conversion applications an extra PROM address input is available and may be used as a polarity control, blanking control or code selector input. The use of a single Am27S19 to convert the outputs of a binary counter to either excess three or gray code format is illustrated below. In this case both codes are generated in true and complemented form simultaneously.



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TRUTH TABLE

ADDRESS					COMPLEMENT				TRUE				
A_4	A_3	A_2	A_1	A_0	Q_7	Q_6	Q_5	Q_4	Q_3	Q_2	Q_1	Q_0	
0	0	0	0	0	1	1	0	0	0	0	1	1	EXCESS THREE CODE
0	0	0	0	1	1	0	1	1	0	1	0	0	
0	0	0	1	0	1	0	1	0	0	1	0	1	
0	0	0	1	1	1	0	0	1	0	1	1	0	
0	0	1	0	0	1	0	0	0	0	1	1	1	
0	0	1	0	1	0	1	1	1	1	0	0	0	
0	0	1	1	0	0	1	1	0	1	0	0	1	
0	0	1	1	1	0	1	0	1	1	0	1	0	
0	1	0	0	0	0	1	0	0	1	0	1	1	
0	1	0	0	1	0	0	1	1	1	1	0	0	
0	1	0	1	0	X	X	X	X	X	X	X	X	
0	1	0	1	1	X	X	X	X	X	X	X	X	
0	1	1	0	0	X	X	X	X	X	X	X	X	
0	1	1	0	1	X	X	X	X	X	X	X	X	
0	1	1	1	0	X	X	X	X	X	X	X	X	
0	1	1	1	1	X	X	X	X	X	X	X	X	
1	0	0	0	0	1	1	1	1	0	0	0	0	GRAY CODE
1	0	0	0	1	1	1	1	0	0	0	0	1	
1	0	0	1	0	1	1	0	0	0	0	1	1	
1	0	0	1	1	1	1	0	1	0	0	1	0	
1	0	1	0	0	1	0	0	1	0	1	1	0	
1	0	1	0	1	1	0	0	0	0	1	1	1	
1	0	1	1	0	1	0	1	0	0	1	0	1	
1	0	1	1	1	1	0	1	1	0	1	0	0	
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1	1	0	0	1	0	0	1	0	1	1	0	1	
1	1	0	1	0	0	0	0	0	1	1	1	1	
1	1	0	1	1	0	0	0	1	1	1	1	0	
1	1	1	0	0	0	1	0	1	1	0	1	0	
1	1	1	0	1	0	1	0	0	1	0	1	1	
1	1	1	1	0	0	1	1	0	1	0	0	0	
1	1	1	1	1	0	1	1	1	1	0	0	0	

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ABSOLUTE MAXIMUM RATINGS

Storage Temperature ..... −65 to +150°C
Ambient Temperature with
Power Applied ..... −55 to +125°C
Supply Voltage ..... −0.5 V to +7.0 V
DC Voltage Applied to Outputs
(Except During Programming) ..... −0.5 to +V_{CC} Max.
DC Voltage Applied to Outputs
During Programming ..... 21 V
Output Current into Outputs During
Programming (Max. Duration of 1 sec.) ..... 250 mA
DC Input Voltage ..... −0.5 V to 5.5 V
DC Input Current ..... −30 to +5 mA

Stresses above those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to absolute maximum ratings for extended periods may affect device reliability.

OPERATING RANGES

Commercial (C) Devices
Ambient Temperature (T_A) ..... 0 to +75°C
Supply Voltage (V_{CC}) ..... +4.75 V to +5.25 V
Military (M) Devices*
Case Temperature (T_C) ..... −55 to +125°C
Supply Voltage (V_{CC}) ..... +4.5 V to +5.5 V

Operating ranges define those limits between which the functionality of the device is guaranteed.

*Military products 100% tested at T_C = +25°C, +125°C, and −55°C.

DC CHARACTERISTICS over operating ranges unless otherwise specified (for APL Products, Group A, Subgroups 1, 2, 3 are tested unless otherwise noted)

Parameter Symbol	Parameter Description	Test Conditions			Min.	Typ.	Max.	Unit
V_{OH} (Note 1)	Output HIGH Voltage	V_{CC} = Min., I_{OH} = −2.0 mA V_{IN} = V_{IH} or V_{IL}			2.4			V
V_{OL}	Output LOW Voltage	V_{CC} = Min., I_{OL} = 16 mA V_{IN} = V_{IH} or V_{IL}					0.45	V
V_{IH}	Input HIGH Level	Guaranteed input logical HIGH voltage for all inputs (Note 2)			2.0			V
V_{IL}	Input LOW Level	Guaranteed input logical LOW voltage for all inputs (Note 2)					0.8	V
I_{IL}	Input LOW Current	V_{CC} = Max., V_{IN} = 0.45 V					−0.250	mA
I_{IH}	Input HIGH Current	V_{CC} = Max., V_{IN} = 2.7 V					25	μA
I_{SC} (Note 1)	Output Short-Circuit Current	V_{CC} = Max., V_{OUT} = 0.0 V (Note 3)			−20		−90	mA
I_{CC}	Power Supply Current	All inputs = GND, V_{CC} = Max.		27S Devices			115	mA
				27LS Devices			80	
V_I	Input Clamp Voltage	V_{CC} = Min., I_{IN} = −18 mA					−1.2	V
I_{CEX}	Output Leakage Current	V_{CC} = Max. $\overline{V_S}$ = 2.4 V	(Note 1)	V_O = V_{CC}			40	μA
				V_O = 0.4 V			−40	
C_{IN}	Input Capacitance	V_{CC} = 5.00 V., T_A = 25°C V_{IN}/V_{OUT} = 2.0 V. @ f = 1 MHz (Note 4)				4		pF
C_{OUT}	Output Capacitance					8		

Notes: 1. This applies to three-state devices only.
2. V_{IL} and V_{IH} are input conditions of output tests and are not themselves directly tested. V_{IL} and V_{IH} are absolute voltages with respect to device ground and include all overshoots due to system and/or tester noise. Do not attempt to test these values without suitable equipment.
3. Not more than one output should be shorted at a time. Duration of the short circuit should not be more than one second.
4. These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.

SWITCHING CHARACTERISTICS over operating ranges unless otherwise specified (for APL Products, Group A, Subgroups 9, 10, 11 are tested unless otherwise noted*)

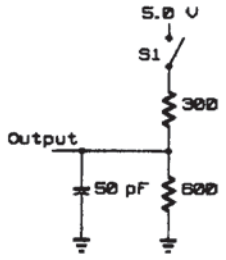
No.	Parameter Symbol	Parameter Description	Version	COM'L		MIL		Unit
				Min.	Max.	Min.	Max.	
1	TAVQV	Address Valid to Output Valid Access Time	SA		15		20	ns
			A		25		35	
			STD		40		50	
			LS		55		70	
2	TGVQZ	Delay from Output Enable Valid to Output Hi-Z	SA		13		20	ns
			A		20		25	
			STD		25		30	
			LS		40		50	
3	TGVQV	Delay from Output Enable Valid to Output Valid	SA		13		20	ns
			A		20		25	
			STD		25		30	
			LS		40		50	

See also Switching Test Circuits.

Notes: 1. Tests are performed with input transition time of 5 ns or less, timing reference levels of 1.5 V, and input pulse levels of 0 to 3.0 V using test load in A under Switching Test Circuits.
2. TGVQZ is measured at steady state HIGH output voltage −0.5 V and steady state LOW output voltage +0.5 V output levels using the test load in B under Switching Test Circuits.

*Subgroups 7 and 8 apply to functional tests.

SWITCHING TEST CIRCUITS



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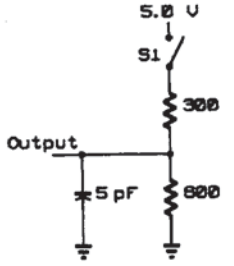
A. Output Load for all tests except TGVQZ



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B. Output Load for TGVQZ

Notes: 1. All device test loads should be located within 2" of device output pin.
2. S_1 is open for Output Data HIGH to Hi-Z and Hi-Z to Output Data HIGH tests. S_1 is closed for all other AC tests.
3. Load capacitance includes all stray and fixture capacitance.

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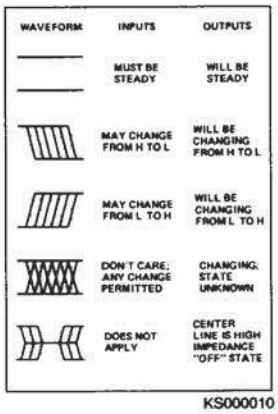
SWITCHING WAVEFORMS

KEY TO SWITCHING WAVEFORMS



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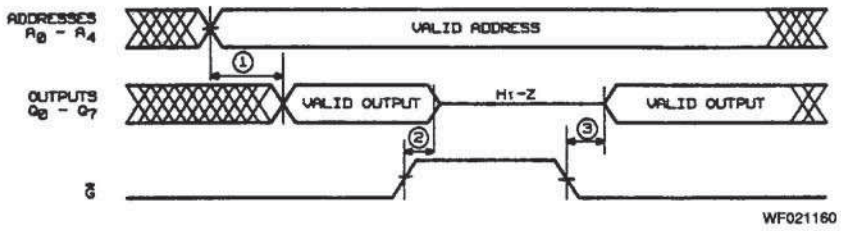

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